POWER TRANSISTORS
5 Amp, 300V, Planar NPN

JAN, JANTX, & JANTXV 2N5664
JAN, JANTX, & JANTXV 2N5665
JAN, JANTX, & JANTXV 2N5666
JAN, JANTX, & JANTXV 2N5667

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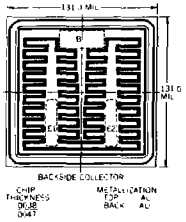
FEATURES
- Meets MIL-S-19500/455
- Collector-Base Voltage: up to 400V
- D.C. Collector Current: 5A
- Peak Collector Current: 10A
- Fast Switching



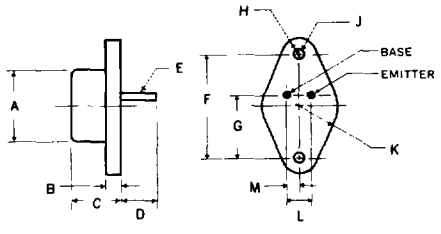
DESCRIPTION
Unitrode high voltage transistors provide a unique combination of low saturation voltage, fast switching, and excellent gain. They are ideally suited for off-line power supply designs and other applications where the increased voltage rating adds to system reliability.

ABSOLUTE MAXIMUM RATINGS

	JAN, JANTX, & JANTXV 2N5664	JAN, JANTX, & JANTXV 2N5665	JAN, JANTX, & JANTXV 2N5666	JAN, JANTX, & JANTXV 2N5667
Collector-Base Voltage, V_{CBO}	250V	400V	250V	400V
Collector-Emitter Voltage, V_{CEO}	200V	300V	200V	300V
Emitter-Base Voltage, V_{EBO}	6V	6V	6V	6V
D.C. Collector Current, I_C	5A	5A	5A	5A
Peak Collector Current, I_C	10A	10A	10A	10A
Power Dissipation				
25°C Ambient	2.5W	2.5W	1.2W	1.2W
100°C Case	30W	30W	15W	15W
Operating and Storage Temperature Range	—65°C to 200°C			

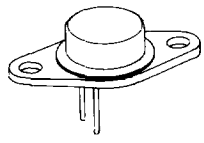
MECHANICAL SPECIFICATIONS

JAN, JANTX, & JANTXV 2N5664 JAN, JANTX, & JANTXV 2N5665

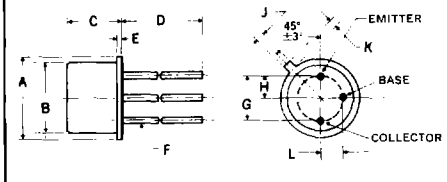


	INCHES	MILLIMETERS
A	.620 MAX.	15.75 MAX.
B	.050 - 075	1.27 - 1.90
C	.250 - .340	6.35 - 8.63
D	.360 MIN.	9.14 MIN.
E	.028 - 034 DIA.	.711 - 863
F	.958 - .962	24.33 - 24.43
G	.570 - 590	14.47 - 14.98
H	.145 MAX. RAD.	3.68 MAX. RAD.
J	.142 - .152 DIA.	3.60 - 3.86 DIA.
K	.350 MAX. RAD.	8.89 MAX. RAD.
L	.190 - .210	4.82 - 5.33
M	.093 - .107	2.36 - 2.72

TO-66



JAN, JANTX, & JANTXV 2N5666 JAN, JANTX, & JANTXV 2N5667



	INCHES	MILLIMETERS
A	335-.370	8.51-9.40
B	305-.335	7.75-8.51
C	.240-.260	6.09-6.60
D	1.5 MIN.	38.10 MIN.
E	.010-.030	.254-.762
F	.017 ± .002 .001	432 ± .051 .025
G	.200	5.08
H	.100	2.54
J	.031±.003	.787±.076
K	.029-.045	.736-1.14
L	.100	2.54

TO-5

UNITRODE

ELECTRICAL SPECIFICATIONS (at 25°C unless noted)
2N5664, 2N5666

Test	Symbol	Min	Max	Units	455 Sub group	MIL-STD-750 Method	MIL-STD-750 Test conditions
Visual and mechanical					A-1	2071	See Mechanical Data
25°C							
Collector-Emitter Breakdown Voltage (Note 1)	BV_{CER}*	250	—	Vdc	A-2	3011	I_C = 10mAdc; R_{BE} = 100Ω, Cond. B
Collector-Emitter Breakdown Voltage (Note 1)	BV_{CEO}*	200	—	Vdc	A-2	3011	I_C = 10mAdc; Cond. D
Emitter-Base Breakdown Voltage	BV_{EBO}*	6.0	—	Vdc	A-2	3026	I_E = 10μAdc; Cond. D
Collector-Emitter Cutoff Current	I_{CES}	—	0.2	μAdc	A-2	3041	V_{CE} = 200 Vdc; Cond. C
Collector-Base Cutoff Current	I_{CBO}	—	0.1	μAdc	A-2	3036	V_{CB} = 200Vdc; Cond. D
Collector-Base Cutoff Current	I_{CBO}	—	1.0	mAdc	A-2	3036	V_{CB} = 250Vdc; Cond. D
D.C. Current Gain (Note 1)	h_{FE}*	40	—	—	A-3	3076	I_C = 0.5Adc, V_{CE} = 2Vdc
D.C. Current Gain (Note 1)	h_{FE}*	40	120	—	A-3	3076	I_C = 1Adc, V_{CE} = 5Vdc
D.C. Current Gain (Note 1)	h_{FE}*	15	—	—	A-3	3076	I_C = 3Adc, V_{CE} = 5Vdc
D.C. Current Gain (Note 1)	h_{FE}	5	—	—	A-3	3076	I_C = 5Adc, V_{CE} = 5Vdc
Collector Saturation Voltage (Note 1)	V_{CE} (sat)*	—	0.4	Vdc	A-3	3071	I_C = 3Adc, I_B = 0.3Adc
Collector Saturation Voltage (Note 1)	V_{CE} (sat)	—	1.0	Vdc	A-3	3071	I_C = 5Adc, I_B = 1Adc
Base Saturation Voltage (Note 1)	V_{BE} (sat)*	—	1.2	Vdc	A-3	3066	I_C = 3Adc, I_B = 0.3Adc; Cond. A
Base Saturation Voltage (Note 1)	V_{BE} (sat)	—	1.5	Vdc	A-3	3066	I_C = 5Adc, I_B = 1Adc; Cond. A
Gain-Bandwith Product	f_t*	20	70	MHz	A-4	3306	I_C = 0.5Adc, V_{CE} = 5Vdc, f = 10MHz
Output Capacitance	C_{ob}	—	120	pf	A-4	3236	V_{CB} = 10Vdc, I_E = 0, f = 1MHz
Thermal Resistance	θ_{J-C}				C-1	3151	
2N5664		—	3.3	°C/W			
2N5666		—	6.7	°C/W			
Switching Speeds — Turn-on Time	t_{on}*	—	0.25	μs	A-4	—	I_C = 1Adc
Switching Speeds — Turn-off Time	t_{off}*	—	1.5	μs	A-4	—	
100°C							
Forward Biased Second Breakdown 2N5664	$I_{S/B}$	5	—	Adc	B-6	3051	V_{CE} = 6Vdc, t = 1sec
	$I_{S/B}$	0.75	—	Adc	B-6	3051	V_{CE} = 40Vdc, t = 1sec
	$I_{S/B}$	43	—	mAdc	B-6	3051	V_{CE} = 200Vdc, t = 1sec
2N5666	$I_{S/B}$	5	—	Adc	B-7	3051	V_{CE} = 3Vdc, t = 1sec
	$I_{S/B}$	0.4	—	Adc	B-7	3051	V_{CE} = 37.5Vdc, t = 1sec
	$I_{S/B}$	27	—	mAdc	B-7	3051	V_{CE} = 200Vdc, t = 1sec
Unclamped Reverse Biased Second Breakdown	$E_{S/B}$	0.81	—	mj	B-8	3053	I_C = 5Adc, L = 065mh
Clamped Reverse Biased Second Breakdown	$E_{S/B}$	500	—	mj	B-9	3053	I_C = 5Adc, L = 40mh, V_{clamp} = 200V
150°C							
Collector-Emitter Cutoff Current	I_{CES}	—	100	μAdc	A-5	3041	V_{CE} = 200 Vdc, Cond. C
−65°C							
D.C. Current Gain (Note 1)	h_{FE}	15	—	—	A-6	3076	I_C = 1Adc, V_{CE} = 5Vdc

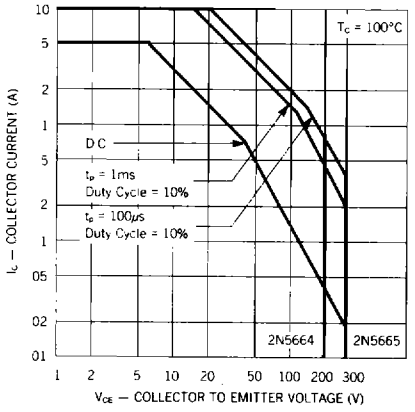
Notes:
1. Pulse width = 300μS; duty cycle ≤2%.
* Those parameters marked with a * are JEDEC registered and devices meeting these specifications are available as commercial 2N devices.

ELECTRICAL SPECIFICATIONS (at 25°C unless noted)
2N5665, 2N5667

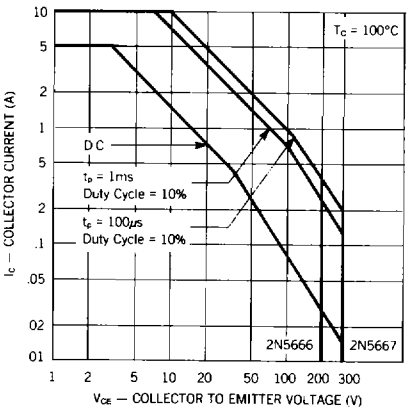
Test	Symbol	Min.	Max.	Units	455 Sub group	MIL-STD-750 Method	MIL-STD-750 Test conditions
Visual and mechanical					A-1	2071	See Mechanical Data
25°C							
Collector-Emitter Breakdown Voltage (Note 1)	BV_{CER}*	400	—	Vdc	A-2	3011	I_C = 10mAdc; R_{BE} = 100 Ω, Cond. B
Collector-Emitter Breakdown Voltage (Note 1)	BV_{CEO}*	300	—	Vdc	A-2	3011	I_C = 10mAdc; Cond. D
Emitter-Base Breakdown Voltage	BV_{EBO}*	6	—	Vdc	A-2	3026	I_E = 10μAdc; Cond. D
Collector-Emitter Cutoff Current	I_{CES}	—	0.2	μAdc	A-2	3041	V_{CE} = 300 Vdc; Cond. C
Collector-Base Cutoff Current	I_{CBC}	—	0.1	μAdc	A-2	3036	V_{CB} = 300Vdc; Cond. D
Collector-Base Cutoff Current	I_{CBO}	—	1.0	mAdc	A-2	3036	V_{CB} = 400Vdc; Cond. D
D.C. Current Gain (Note 1)	h_{FE}*	25	—	—	A-3	3076	I_C = 0.5Adc, V_{CE} = 2Vdc
D.C. Current Gain (Note 1)	h_{FE}*	25	75	—	A-3	3076	I_C = 1Adc, V_{CE} = 5Vdc
D.C. Current Gain (Note 1)	h_{FE}*	15	—	—	A-3	3076	I_C = 3Adc, V_{CE} = 10Vdc
D.C. Current Gain (Note 1)	h_{FE}	5	—	—	A-3	3076	I_C = 5Adc, V_{CE} = 5Vdc
Collector Saturation Voltage (Note 1)	V_{CE} (sat)*	—	0.4	Vdc	A-3	3071	I_C = 3Adc, I_B = 0.6Adc
Collector Saturation Voltage (Note 1)	V_{CE} (sat)	—	1.0	Vdc	A-3	3071	I_C = 5Adc, I_B = 1Adc
Base Saturation Voltage (Note 1)	V_{BE} (sat)*	—	1.2	Vdc	A-3	3066	I_C = 3Adc, I_B = 0.6Adc; Cond. A
Base Saturation Voltage (Note 1)	V_{BE} (sat)	—	1.5	Vdc	A-3	3066	I_C = 5Adc. I_B = 1Adc; Cond. A
Gain-Bandwith Product	f_T*	20	70	MHz	A-4	3306	I_C = 0.5Adc, V_{CE} = 5Vdc, f = 10MHz
Output Capacitance	C_{ob}	—	90	pf	A-4	3236	V_{CB} = 10Vdc, I_E = 0, f = 1MHz
Thermal Resistance	θ_{J-C}				C-1	3151	
2N5665		—	3.3	°C/W			
2N5667		—	6.7	°C/W			
Switching Speeds — Turn-on time	t_{on}*	—	0.25	μs	A-4	—	I_C = 1Adc
Switching Speeds — Turn-off time	t_{off}*	—	2.0	μs	A-4	—	
100°C							
Forward Biased Second Breakdown 2N5665	$I_{S/B}$	5	—	Adc	B-6	3051	V_{CE} = 6Vdc, t = 1sec
	$I_{S/B}$	0.75	—	Adc	B-6	3051	V_{CE} = 40Vdc, t = 1 sec
	$I_{S/B}$	21	—	mAdc	B-6	3051	V_{CE} = 300Vdc, t = 1sec
2N5667	$I_{S/B}$	5	—	Adc	B-7	3051	V_{CE} = 3Vdc, t = 1sec
	$I_{S/B}$	0.4	—	Adc	B-7	3051	V_{CE} = 37.5Vdc, t = 1sec
	$I_{S/B}$	14	—	mAdc	B-7	3051	V_{CE} = 300Vdc, t = 1sec
Unclamped Reverse Biased Second Breakdown	$E_{S/B}$	0 81	—	mj	B-8	3053	I_C = 5Adc, L = .065mh
Clamped Reverse Biased Second Breakdown	$E_{S/B}$	500	—	mj	B-9	3053	I_C = 5Adc, L = 40mh, V_{clamp} = 300V
150°C							
Collector-Emitter Cutoff Current	I_{CES}	—	100	μAdc	A-5	3041	V_{CE} = 300 Vdc, Cond. C
−65°C							
D.C. Current Gain (Note 1)	h_{FE}	10	—	—	A-6	3076	I_C = 1Adc, V_{CE} = 5Vdc

Notes:
1. Pulse width = 300μS; duty cycle ≤2%.
* Those parameters marked with a * are JEDEC registered and devices meeting these specifications are available as commercial 2N devices.

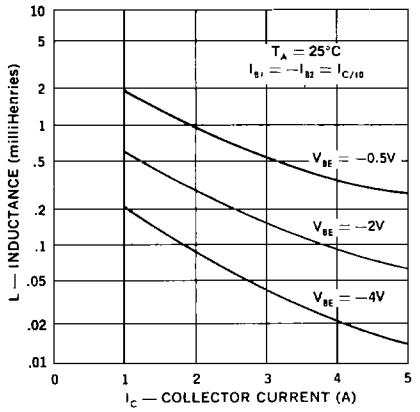
Forward Bias Safe Operating Area 2N5664, 2N5665



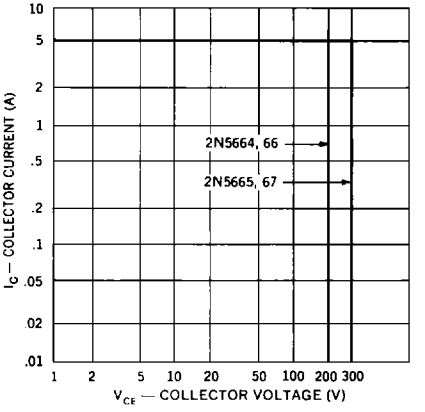
Forward Bias Safe Operating Area 2N5666, 2N5667



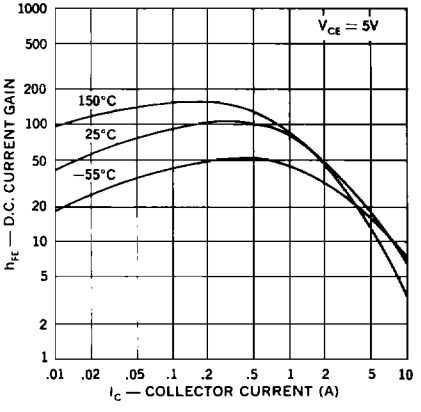
Unclamped Reverse Bias Second Breakdown



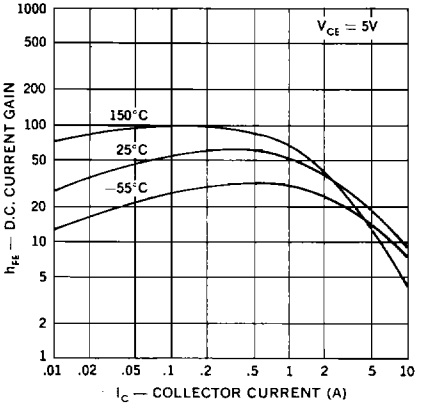
Reverse Bias Safe Operating Area Clamped Inductive Switching



D.C. Current Gain 2N5664, 2N5666



D.C. Current Gain 2N5665, 2N5667



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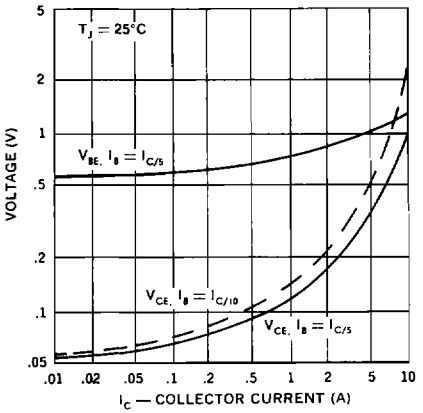
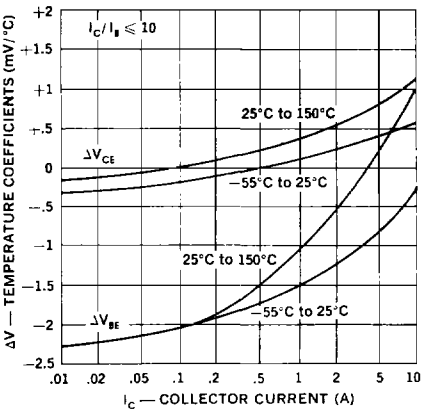
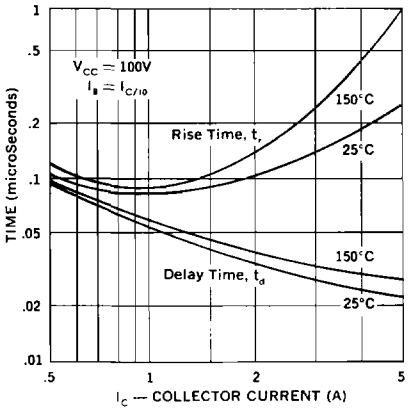
Saturation Voltages



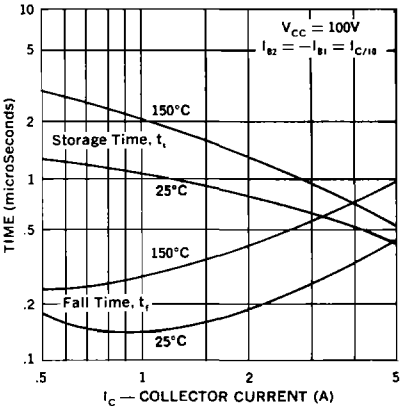
Saturation Voltage Temperature Coefficients



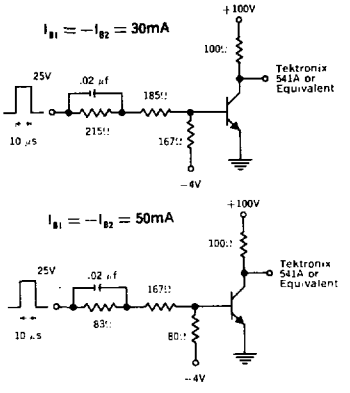
Switching Speed Characteristics



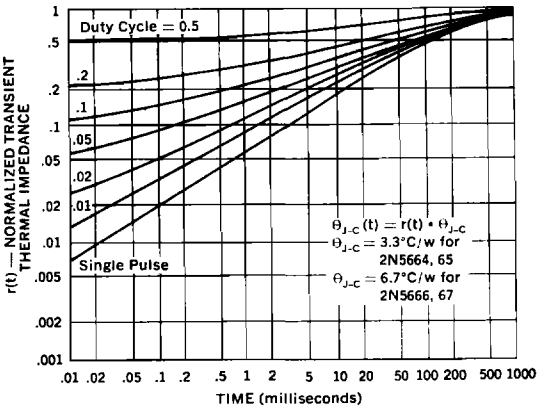
Switching Speed Characteristics



Switching Speed Circuits



Thermal Response



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